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OC81D Transistor Datasheet. Parameters and Characteristics.

Type Designator: OC81D

Material of transistor: Ge

Polarity: PNP

Maximum collector power dissipation (Pc), W: 0.15

Maximum collector-base voltage |Ucb|, V: 16

Maximum collector-emitter voltage |Uce|, V: 16

Maximum emitter-base voltage |Ueb|, V: 3

Maximum collector current |Ic max|, A: 0.01

Maksimalna temperatura (Tj), °C: 80

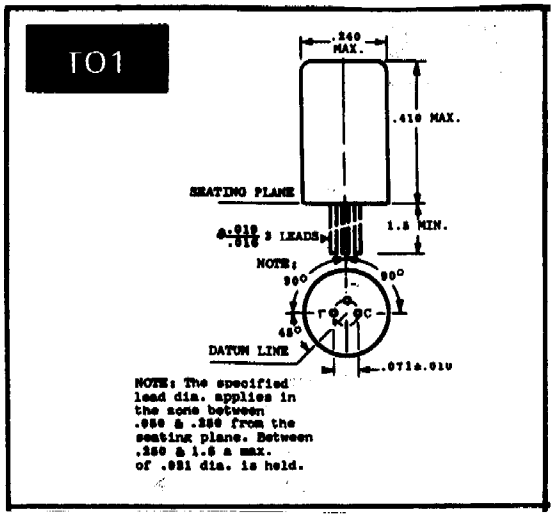
Transition frequency (ft), MHz: 0.2

Collector capacitance (Cc), pF: 40

Forward current transfer ratio (hFE), min: 20

Noise Figure, dB: -

Package of OC81D transistor:



NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

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